PATENT APPLICATION ED STATES PATENT AND TRADEMARK FFICE IN THE U 2825 Group Art Unit Examiner: C. LUU HOSHINO et al. Inventor(s): DEC 0 2 2002 EL00028CDC 835,820 Atty. Dkt. 280192 Appln. No.: 09 Client Ref Series Code 个 Serial No. 1 FABRICATION PROCESSOF Appln. Title: Filed: April 17, 2001 SEMICONDUCTOR'DEVICE Hon. Commissioner of Patents INCLUDING A CVD PROCESS Washington, D.C. 20231 **METAL FILM** Sir: REPLY/AMENDMENT/LETTER December 2, 2002 Date: This is a reply/amendment/letter in the above-identified application and includes the herewith attachment of same date and subject which is incorporated hereinto by reference and the signature below is treated as the signature to the attachment in absence of a signature thereto.

FEE REQUIREMENTS FOR CLAIMS AS AMENDED

1. Small Entity claim							
A. NOT made B. Withdrawn C. made herewith D. made previously  For B & C See Required Separate Paper (Pat-256)	Claims remaining after amendment	Highest nu previously p		Present Extra	Large/Small Entity	Additional Fee	Fee Code Lg/Sm
	140	**	100		¢40/¢0 -	1 . 60	103/203
2. Total Effective Claims	16	**minus	20	0	x \$18/\$9 =	+ \$0	
3. Independent Claims	3	***minus	3	10	x \$84/\$42 =	+ \$0	102/202
4. If amendment enters <u>proper</u> multiple dependent claim(s) into this application for <u>first</u>					. 6000/6440 -	. 60	104/204
time (leave blank if this is a reissue application)					+ \$280/\$140 =	+ \$0	104/204
5. Original due Date: October 1, 2002 NONE							1 15/215
6. Petition is hereby made to extend the original due (1 mo) \$110/\$55 =					. 0400		115/215
date to cover the date this response is filed for which the (2 mos) \$400/\$200 =					+ \$400		116/216 117/217
requisite fee is attached (3 mos) \$920/\$460 =							118/218
(4 mos)   \$1,440/\$720=						-	128/228
			mos)	\$1,960/\$980=		4	
7. Enter any previous extension fee paid since above original due date and subtract					- \$0		
8.					Extension Fee	+ \$400	
9. If Terminal Disclaimer attached, add Rule 20(d) official fee					+ \$110/\$55	+ \$0	148/248
10. If IDS attached requires Official Fee under Rule 97 (c),					+ \$180	+ \$0	126 .
or if Rule 97(d) Requestadd					+ \$180	7 40	126
11. After-Final Request Fee per rules 129(a) and 17(r)					+ \$740/370	+ \$0	146/246
12. No. of additional inventions for examination per Rule 129(b)					x \$740/370 ea	+ \$0	149/249
13. Request for Continued Examination (RCE)					+ \$740/370	+ \$0	1179/1279
14. Petition fee for						+ \$0	
15.					TOTAL FEE = \$400		
16. *If the entry in this space is less than entry in next space, the "Present Extra" result is "0".						PLEASE C	HARGE
17. **If the "Highest number previously paid for" in this space is less than 20, write "20" in this space.						OUR DEP.	
18. ***If the "Highest number previously paid for" in this space is less than 3, write "3" in this space.							
	Our Deposit Account No. 03						
(Our Order No. <u>40258</u>							
CHARGE STATEMENT: The Commissioner is hereby authorized to charge any fee specifically authorized hereafter, or any missing or insufficient fee(s) filed, or asserted to be filed, or which should have been filed herewith or concerning any paper filed hereafter, and which may be required under Rules 16-18 (missing or insufficiencies only) now or hereafter relative to this application and the resulting Official Document under Rule 20, or credit any overpayment, to our Accounting/Order Nos. shown above, for which purpose a duplicate copy of this sheet is attached.							
This CHARGE STATEMENT does not authorize charge of the issue fee until/unless an issue fee transmittal sheet					is Query: Is appeal deadline now? If		
filed.					so, file Notice of Appeals separately.		
	Pillsbury	Winthrop L	LP		<u></u>		
	Intellectu	al Property	Group	)			
P.O. Box 10500		Glenn J. P	•		Reg. No.	28458	
McLean, VA 22102							
Tel: (703) 905-2000	Sig:	4m	5		Fax:	(703) 905-	
					Tel:	(703) 905-	2161

NOTE: File this cover sheet in duplicate with PTO receipt (PAT-103A) and attachments

Atty/Sec: gjp/tnl

DEC 0 2 2002

DEC 0 2 2002 IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re PATENT APPLICATION OF

Confirm

Confirmation No.: 5539

HOSHINO et al.

Group Art Unit: 28

E-raminan C IIII

Appln. No.: 09/835,820

Examiner: C. LUU

Filed: April 17, 2001

Title: FABRICATION PROCESS OF A SEMICONDUCTOR DEVICE INCLUDING A CVD

PROCESS OF A METAL FILM

December 1, 2002 (Sunday) December 2, 2002 (Monday)

**AMENDMENT** 

Hon. Commissioner of Patents Washington, D.C. 20231

Sir:

In response to the Office Action dated July 1, 2002, please amend the above identified application as follows:

## IN THE SPECIFICATION:

Please substitute the following for the paragraphs appearing in the original specification:

Page 4, third full paragraph:

Another object of the present invention is to provide a method for fabricating a

semiconductor device, comprising the steps of:

forming a barrier conductor layer on a substrate;

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